

# **KSD471A**

## **Audio Frequency Power Amplifier**

- Complement to KSB564A
- Collector Current : I<sub>C</sub>=1A
- Collector Power Dissipation : P<sub>C</sub>=800mW
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



# **NPN Epitaxial Silicon Transistor**

## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	1	A
P <sub>C</sub>	Collector Power Dissipation	800	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

## Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0	40			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0	30			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =30V, $I_E$ =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	120		400	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			1.2	V
f <sub>T</sub>	Current Gain BandWidth Product	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA		130		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz		16		pF

# **h**<sub>FE</sub> Classification

Classification	Υ	G	
h <sub>FE</sub>	120 ~ 240	200 ~ 400	

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# **Typical Characteristics**

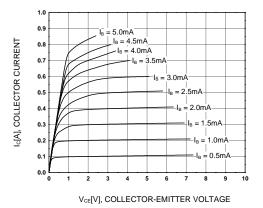


Figure 1. Static Characteristic

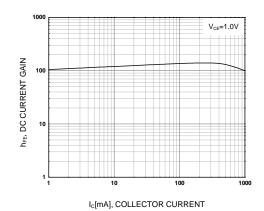


Figure 2. DC current Gain

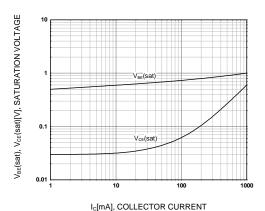


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

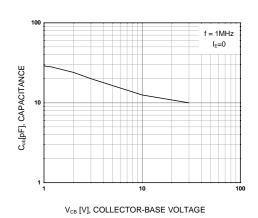


Figure 4. Collector Output Capacitance

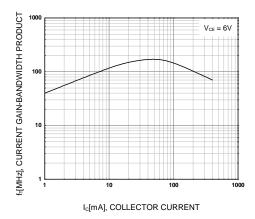


Figure 5. Current Gain Bandwidth Product

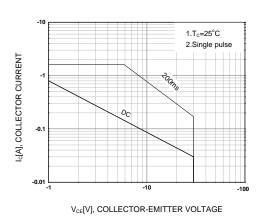
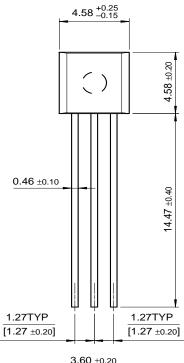


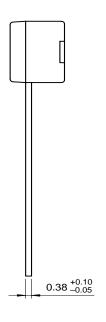
Figure 6. Safe Operating Area

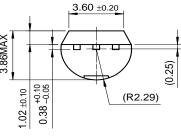
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# **Package Dimensions**

TO-92







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Bottomles	s <sup>TM</sup>	FASTr™	LittleFET™	Power247™	SuperFET™
CoolFETT	М	FPS™	MICROCOUPLER™	PowerSaver™	SuperSOT™-3
CROSSV	$OLT^{TM}$	FRFET™	MicroFET™	PowerTrench <sup>®</sup>	SuperSOT™-6
DOME™		GlobalOptoisolator™	MicroPak™	QFET <sup>®</sup>	SuperSOT™-8
EcoSPAR	$K^{\scriptscriptstyleTM}$	GTO™	MICROWIRE™	QS <sup>TM</sup>	SyncFET™
E <sup>2</sup> CMOS <sup>T</sup>	М	HiSeC™	MSX™	QT Optoelectronics™	TinyLogic <sup>®</sup>
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